2SA0914 (2SA914)

Silicon PNP epitaxial planar type

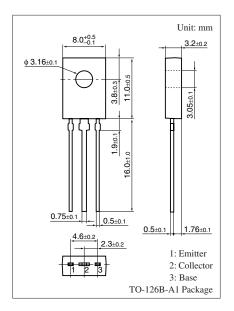
For audio system/pli drive Complementary to 2SC1953

■ Features

- A complementary pair with 2SC1953, is optimum for the predriver stage of a 60 W to 100 W output amplifier
- TO-126B package which requires no insulation plate for installation to the heat sink

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	-150	V	
Collector-emitter voltage (Base open)	V _{CEO}	-150	V	
Emitter-base voltage (Collector open)	V_{EBO}	-5	V	
Collector current	I_C	-50	A	
Peak collector current	I_{CP}	-100	A	
Collector power dissipation	P _C	1.2	W	
Junction temperature	T_{j}	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	



■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

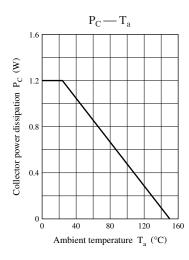
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = -100 \ \mu A, I_B = 0$	-150			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = -10 \ \mu A, I_C = 0$	-5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -100 \text{ V}, I_E = 0$			-1	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	130		330	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -30 \text{ mA}, I_B = -3 \text{ mA}$			-1	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_E = 10 \text{ mA}, f = 200 \text{ MHz}$	70			MHz
Collector output capacitance	C _{ob}	$V_{CB} = -6 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			5	pF
(Common base, input open circuited)						

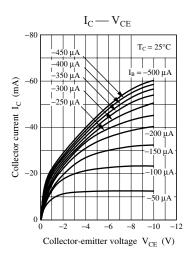
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

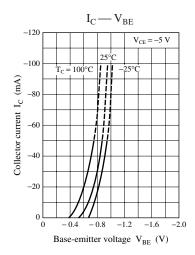
2. *: Rank classification

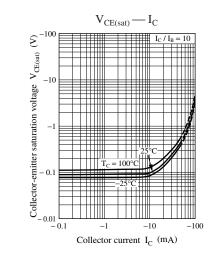
Rank	R	S
h_{FE}	130 to 220	185 to 330

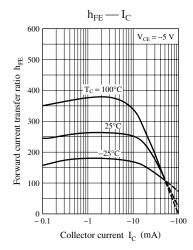
Note) The part number in the parenthesis shows conventional part number.

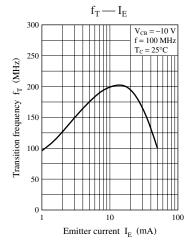


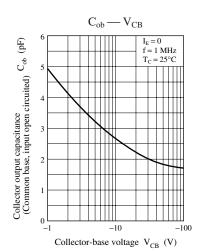












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